

Figure 1

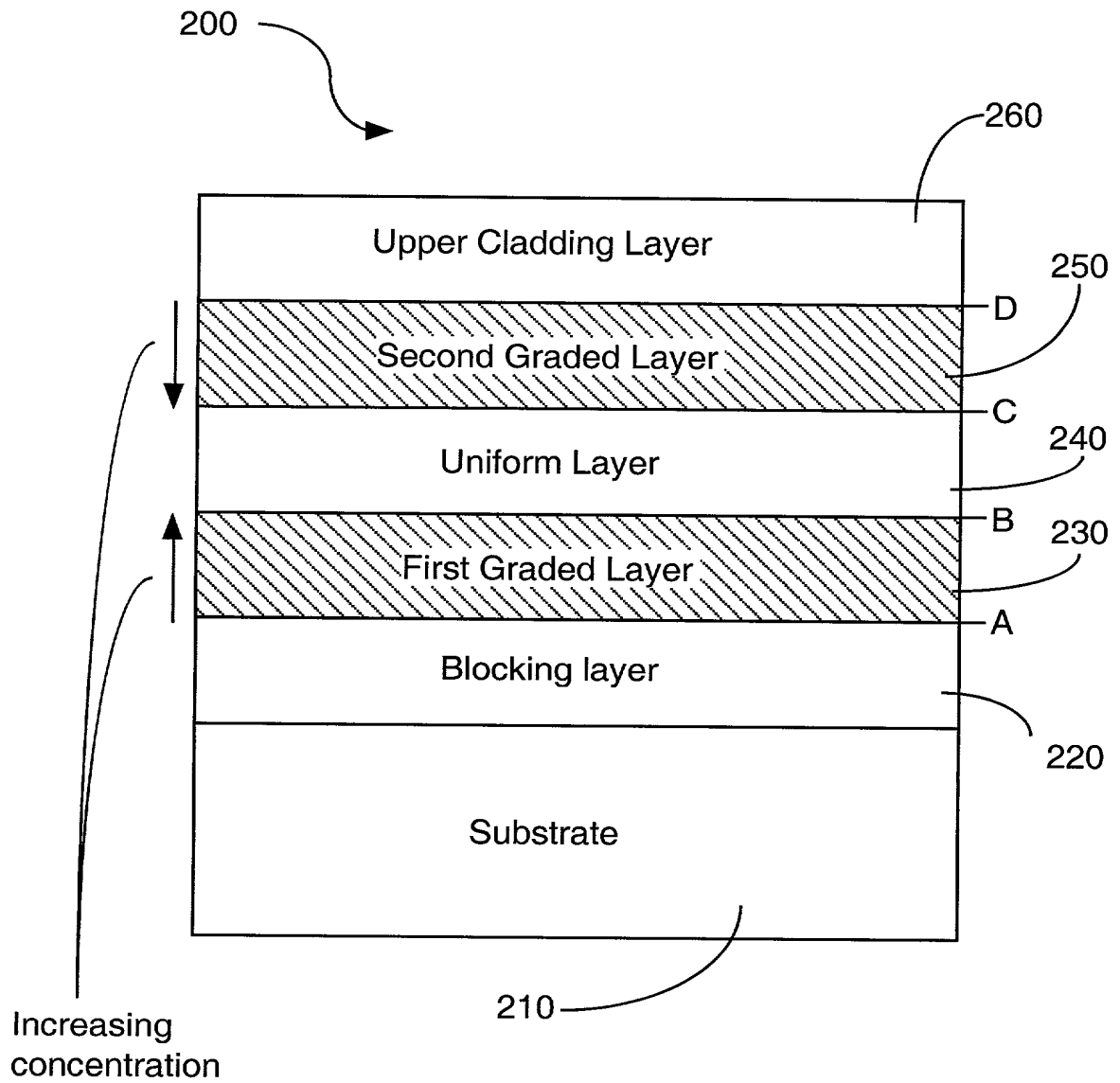


Figure 2

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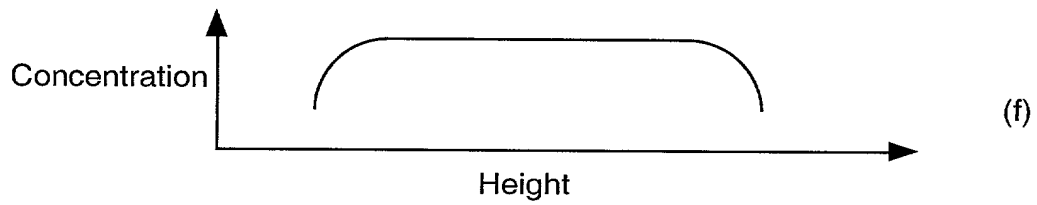
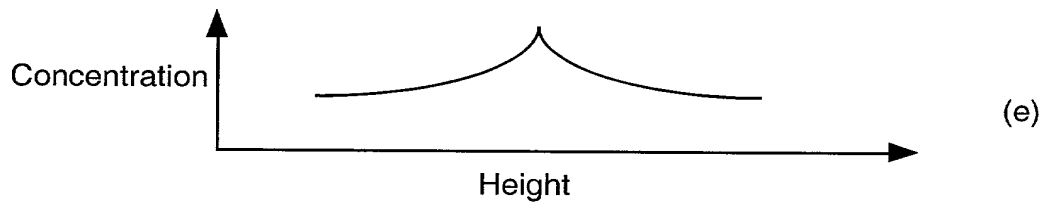
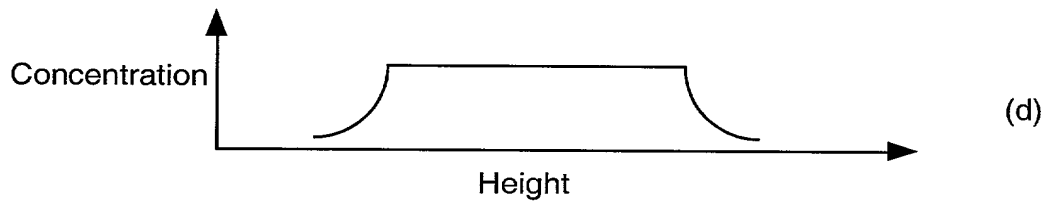
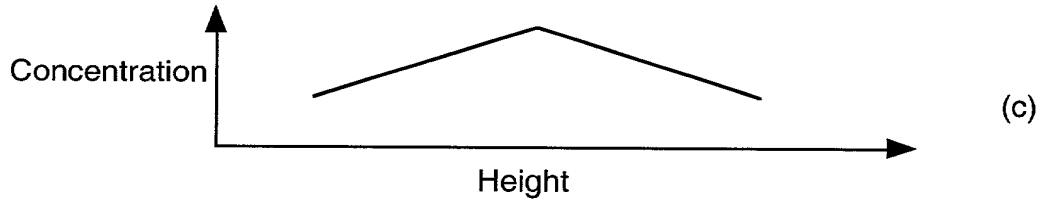
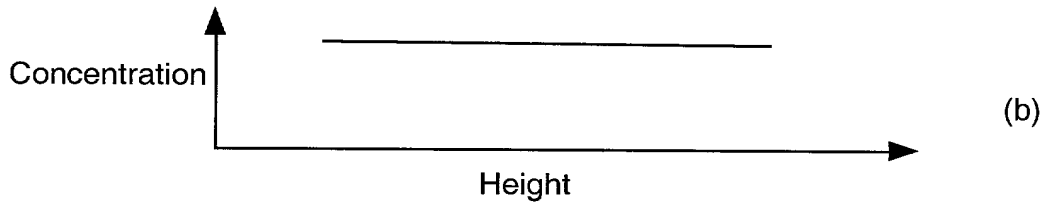
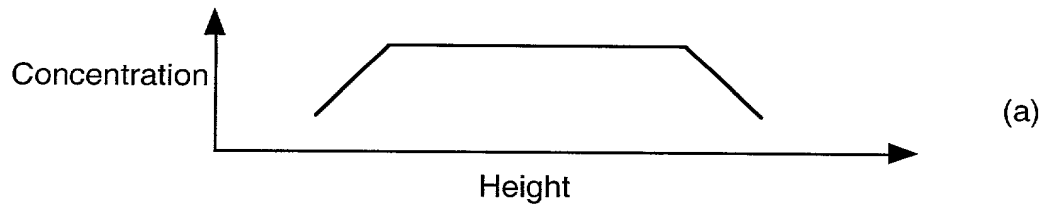
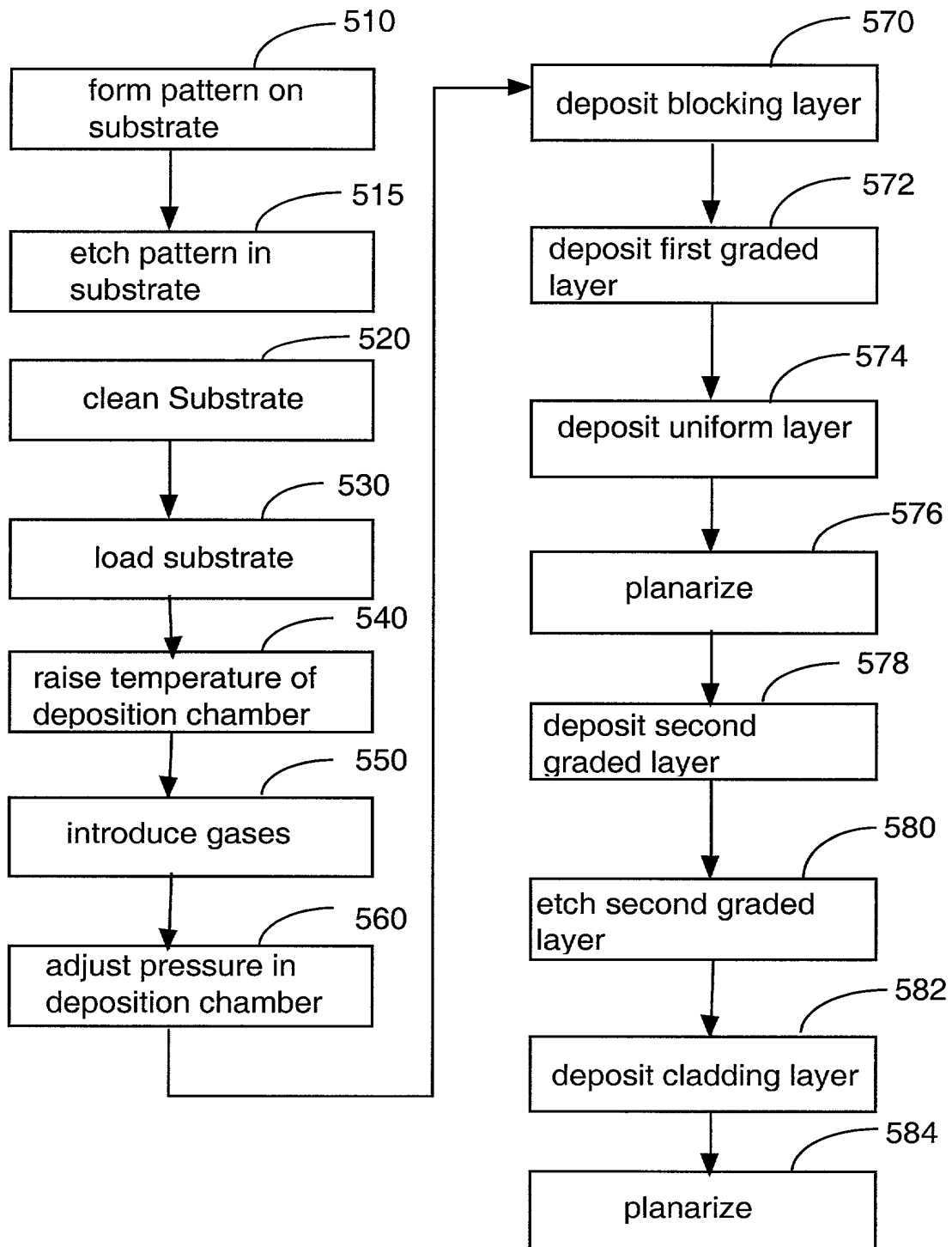


Figure 3

**Figure 4**

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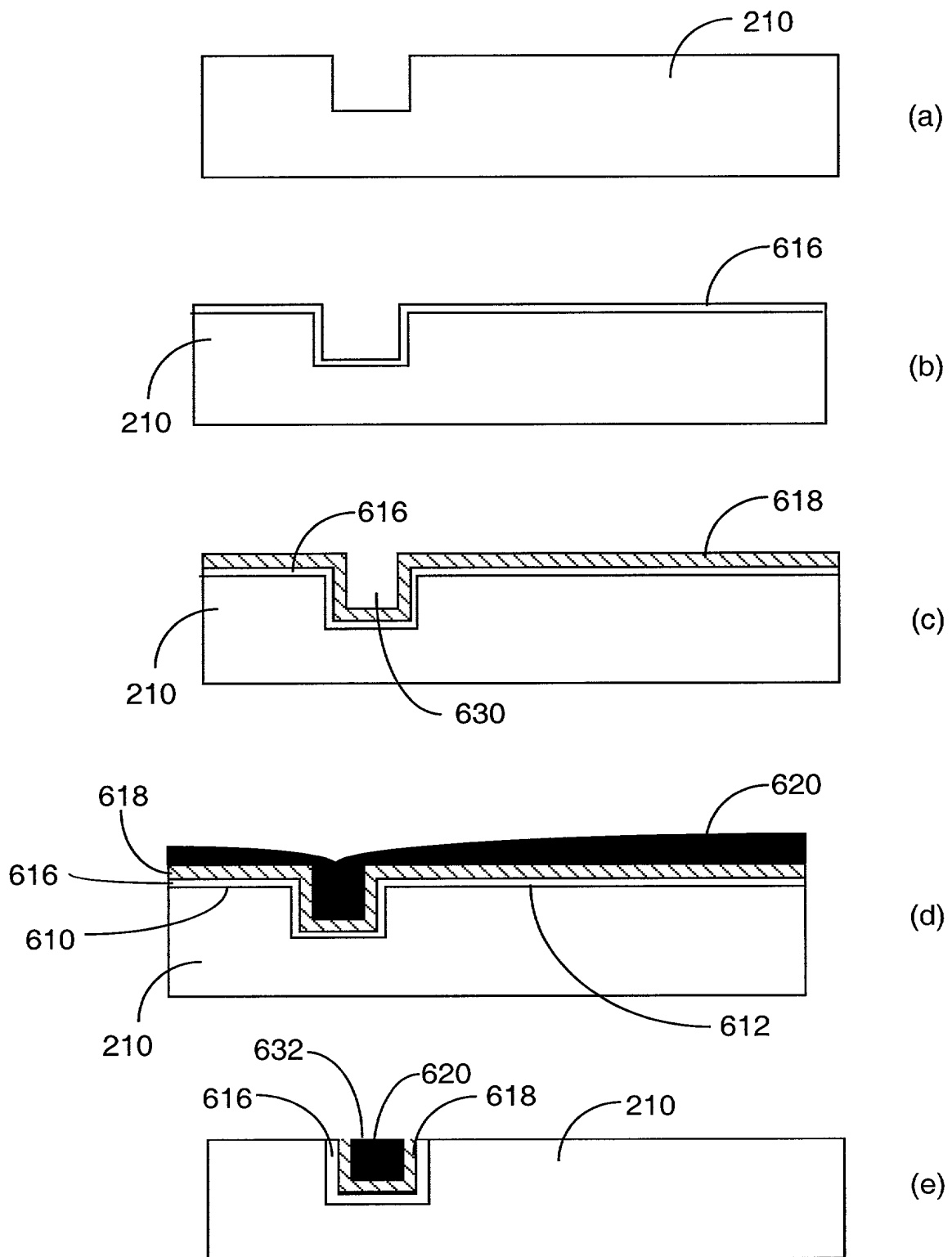


Figure 5

FIG. 5 is a cross-sectional view of a device in accordance with the present invention. The device includes a substrate 210, a first layer 616, a second layer 620, a third layer 622, and a fourth layer 624. A central region 618 is defined by the second layer 620 and the third layer 622. The first layer 616 is disposed on the substrate 210, and the second layer 620 is disposed on the first layer 616. The third layer 622 is disposed on the second layer 620, and the fourth layer 624 is disposed on the third layer 622. The central region 618 is a region where the second layer 620 and the third layer 622 are in contact with each other.

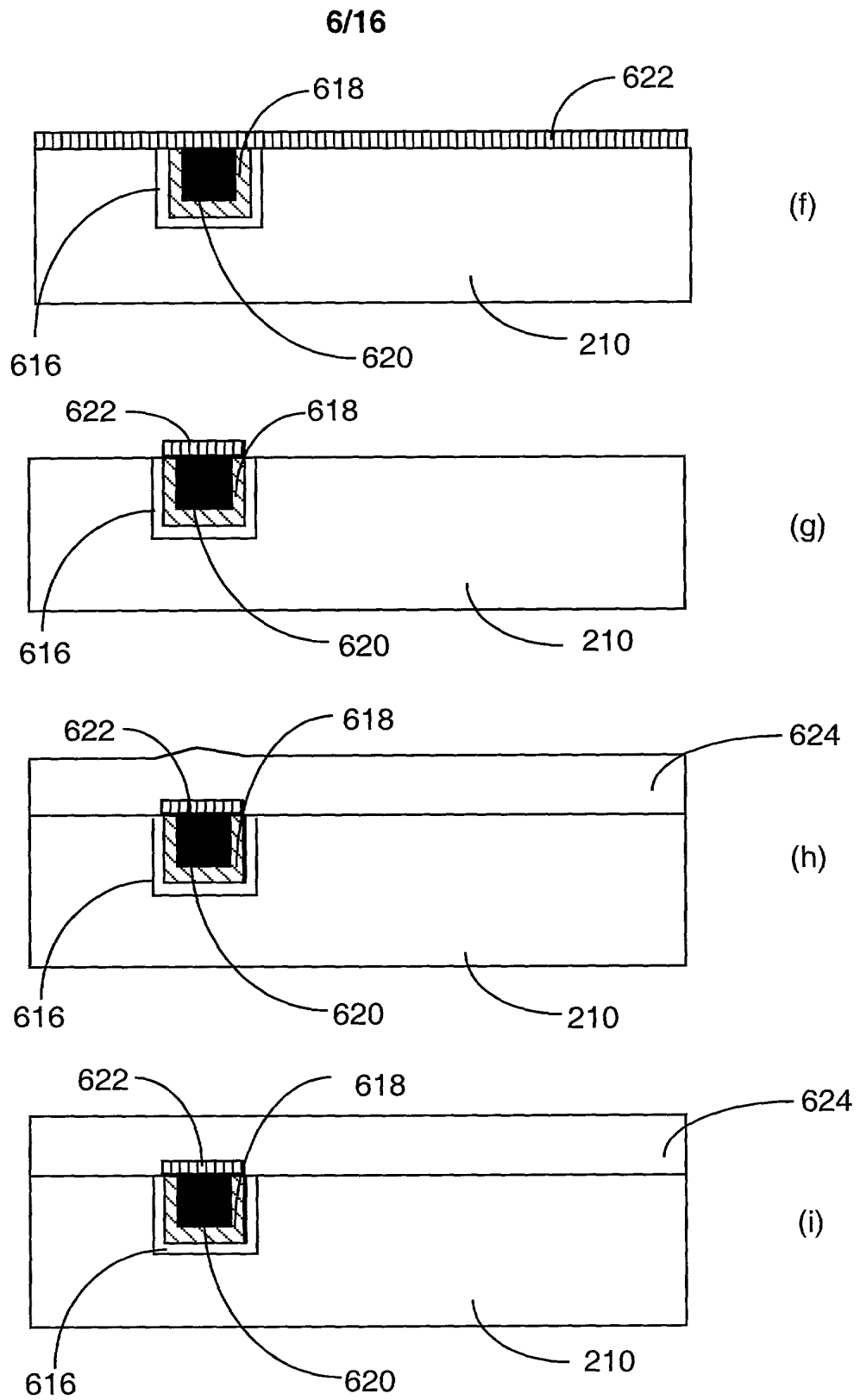
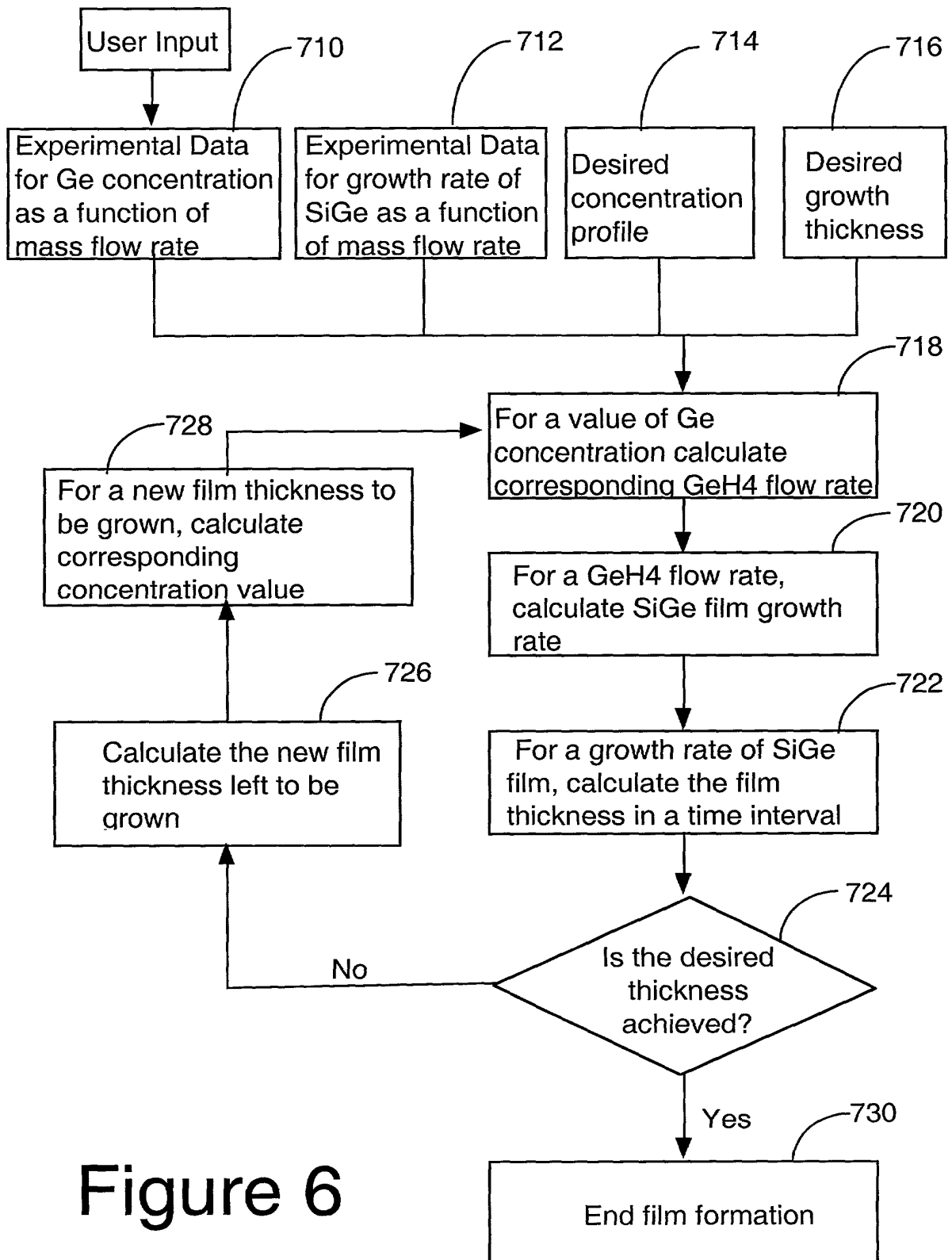


Figure 5

**Figure 6**

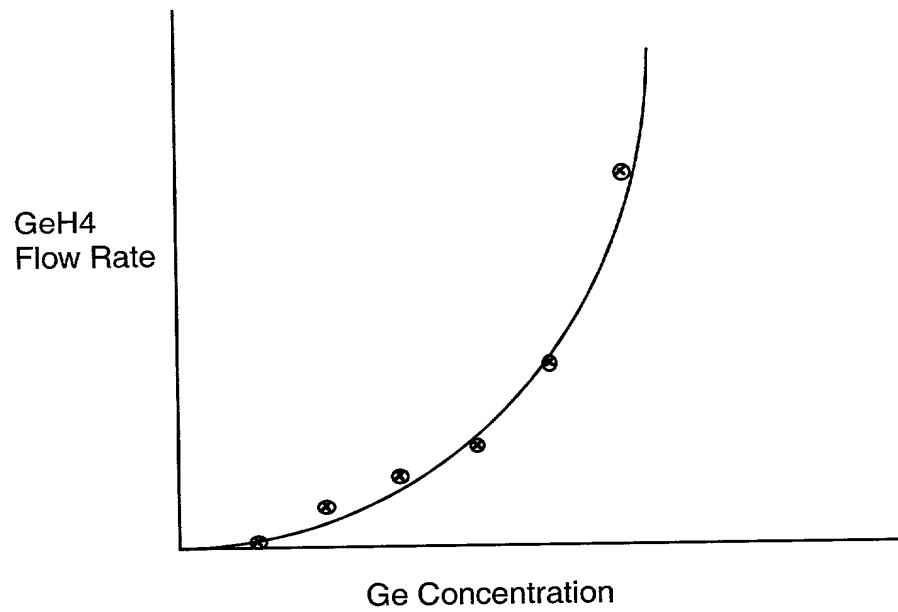


Figure 7

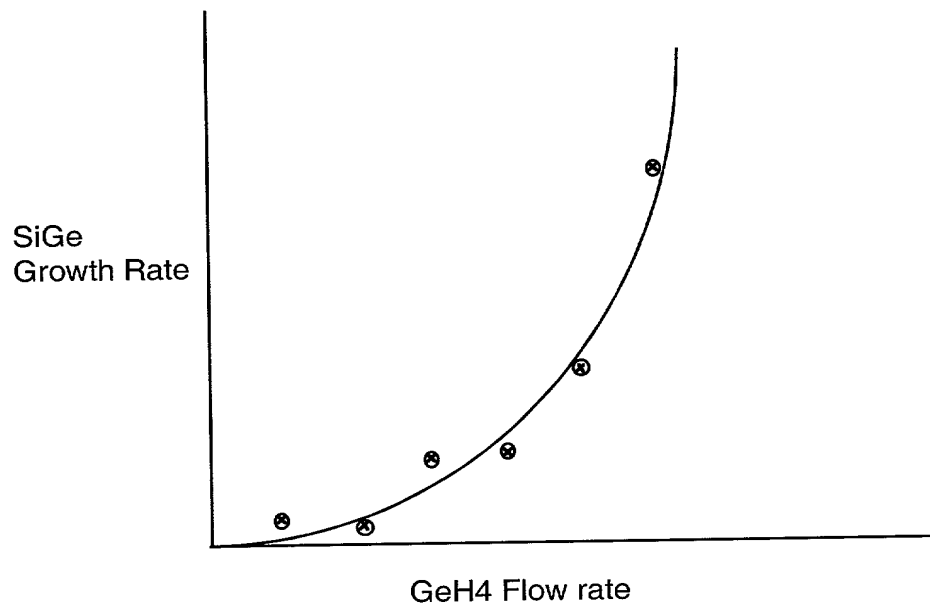


Figure 8

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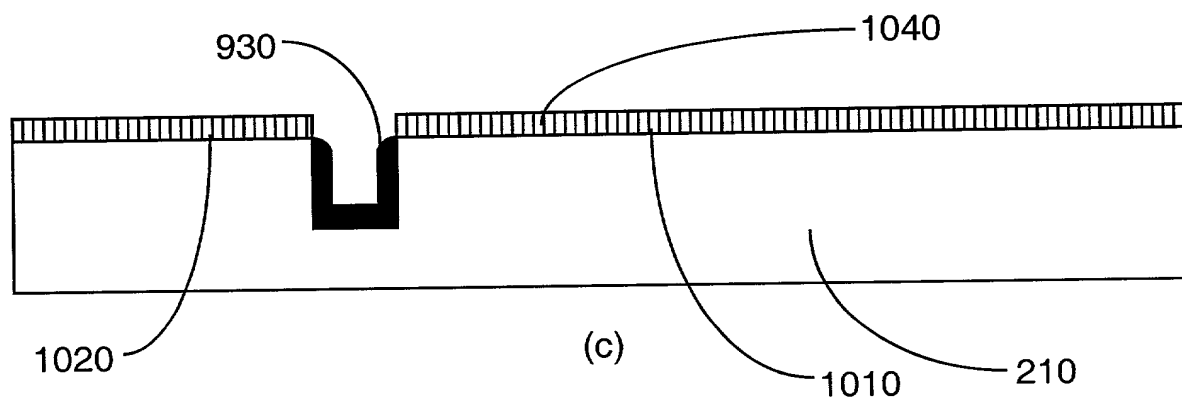
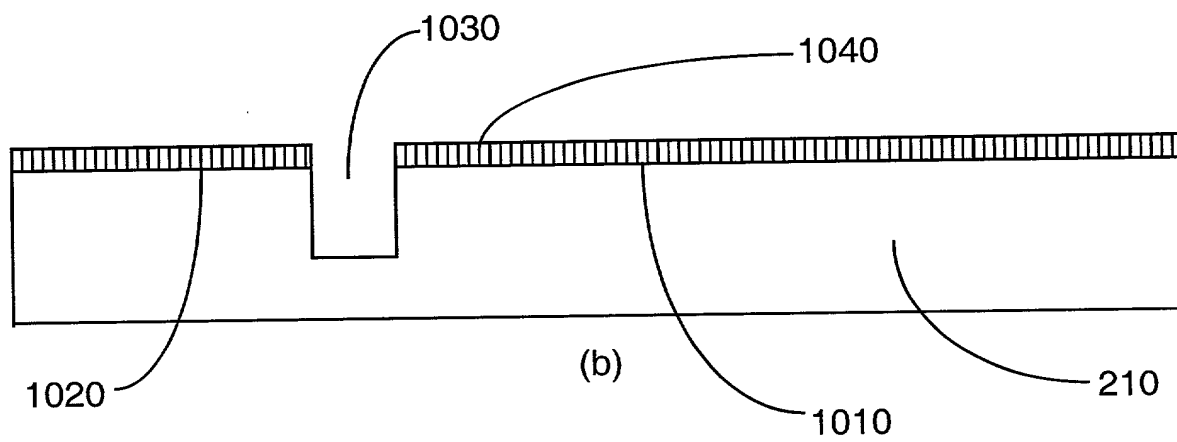
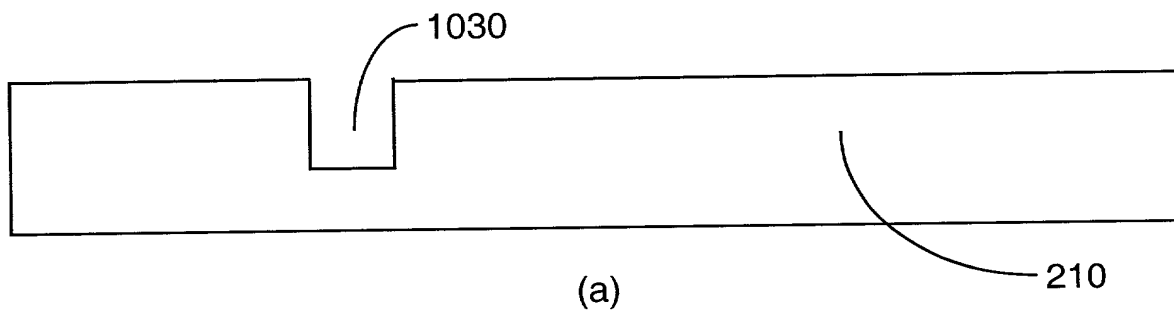


Figure 9

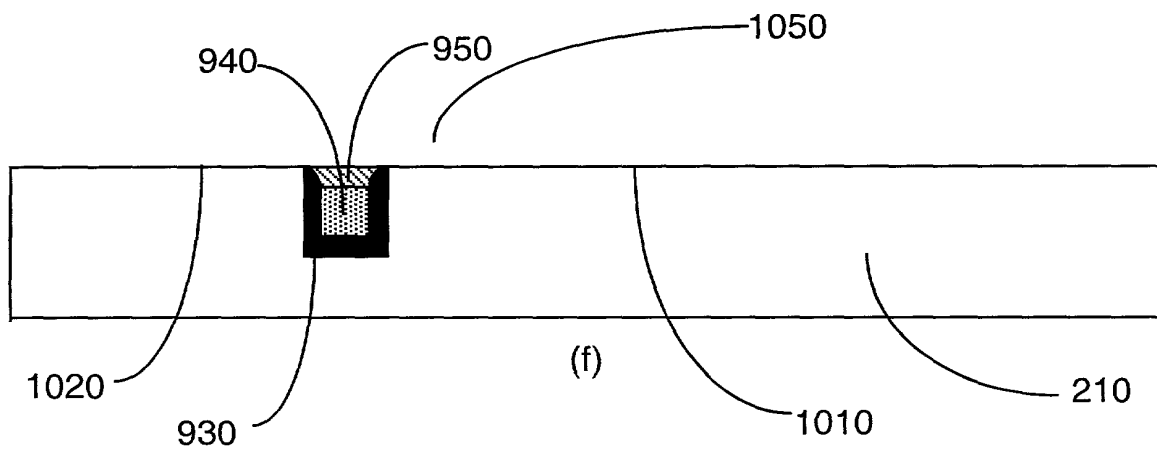
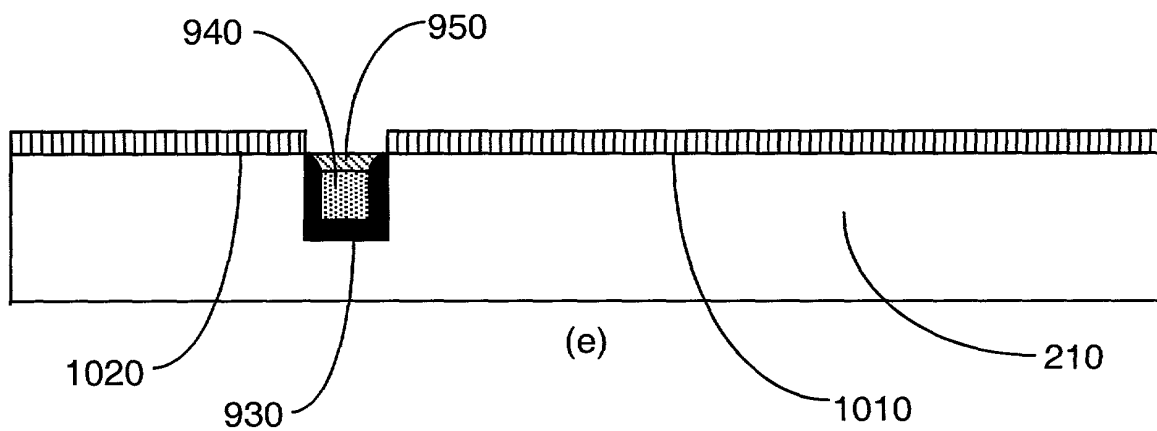
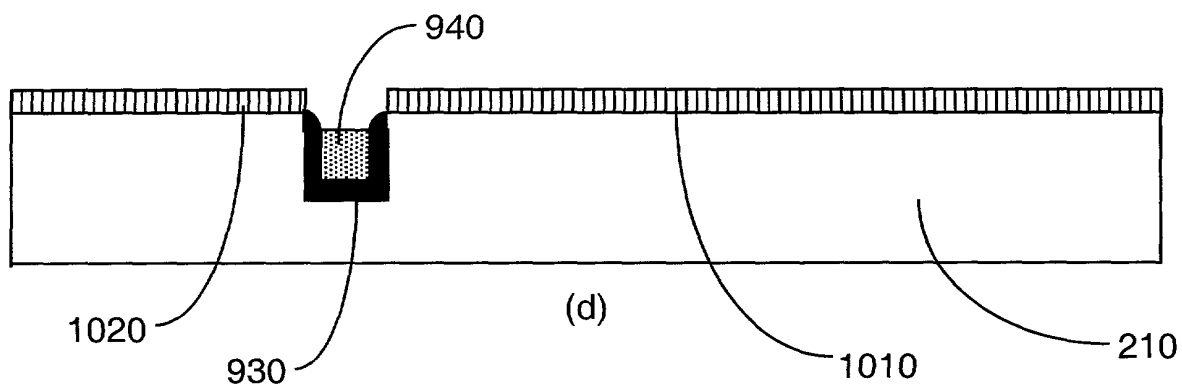


Figure 9

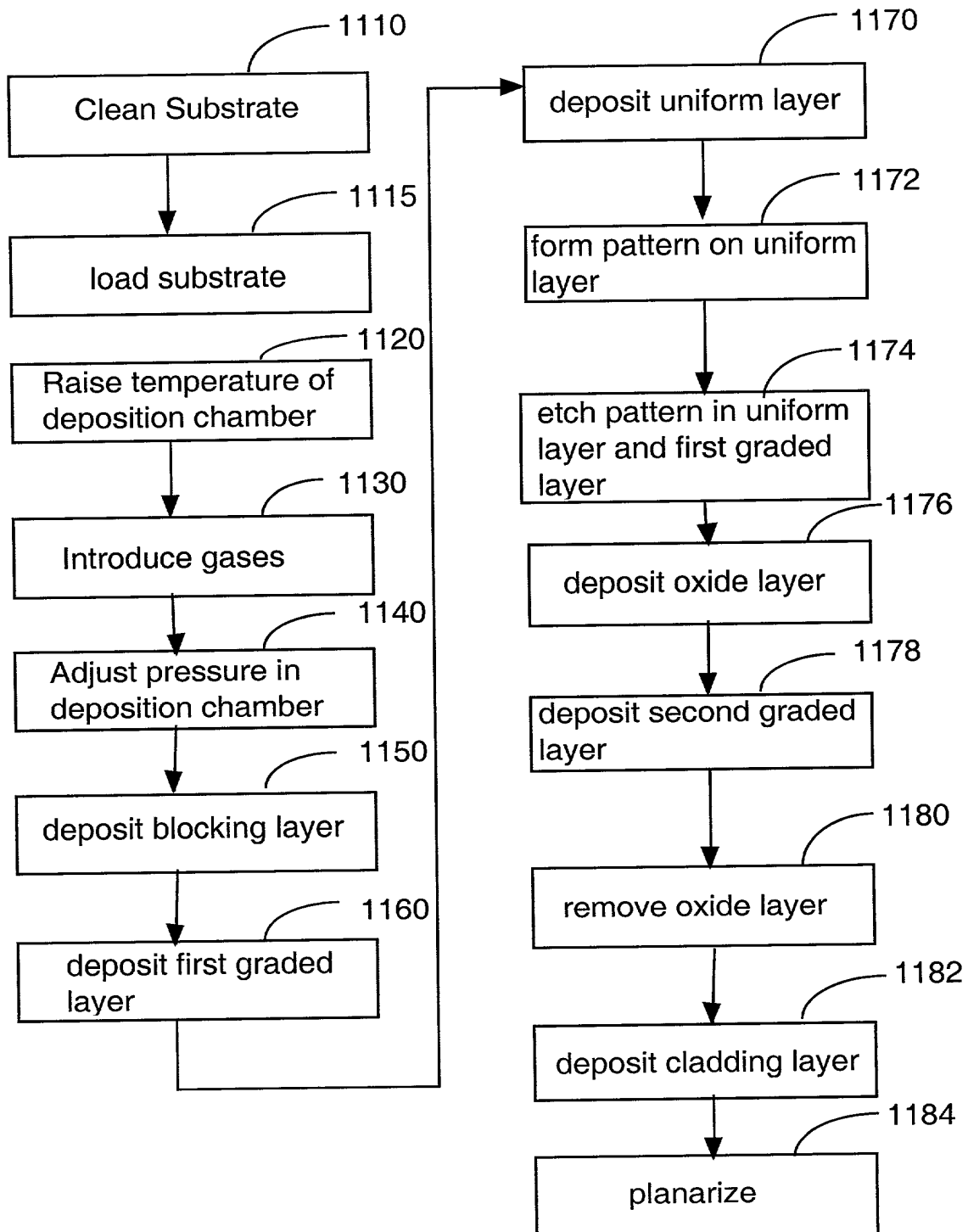


Figure 10

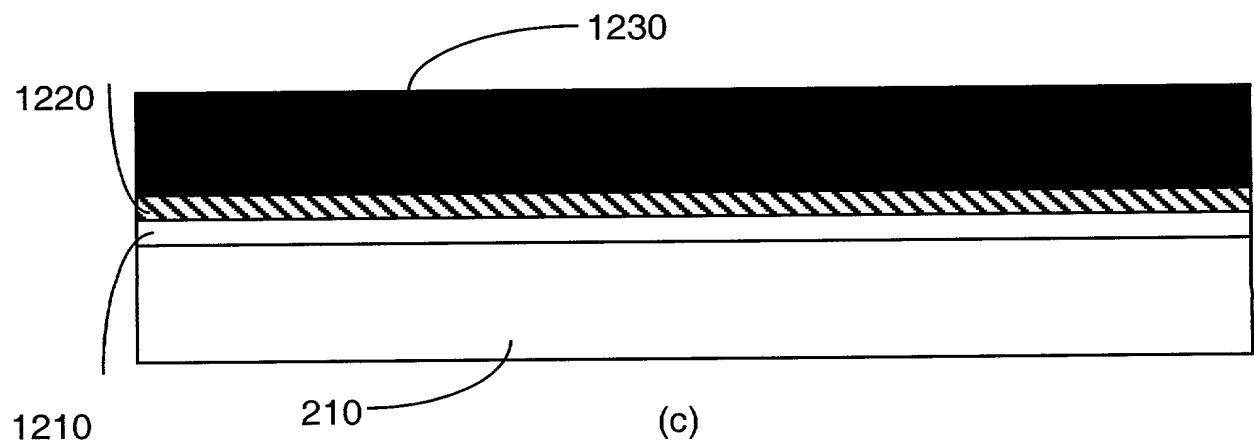
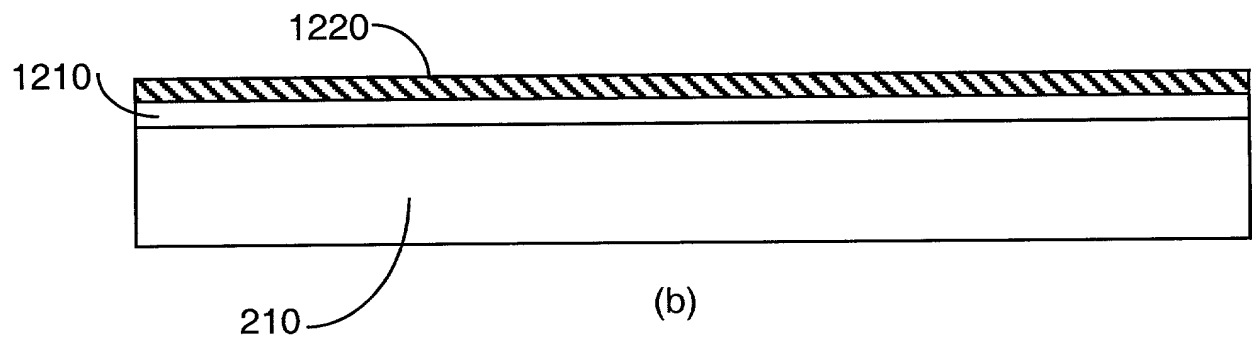
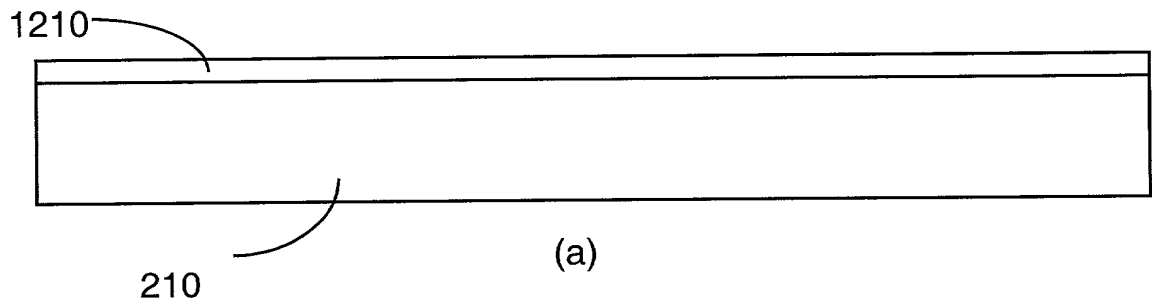


Figure 11

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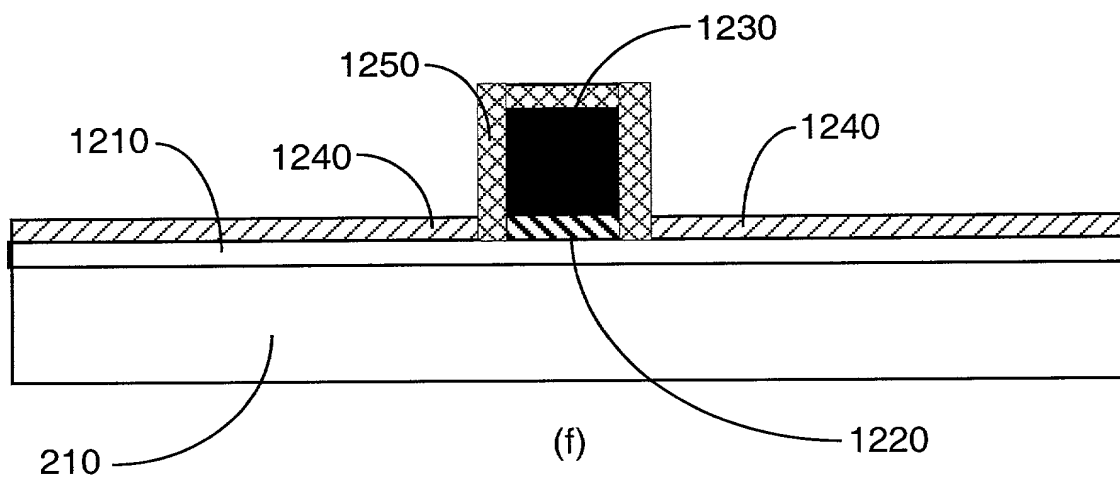
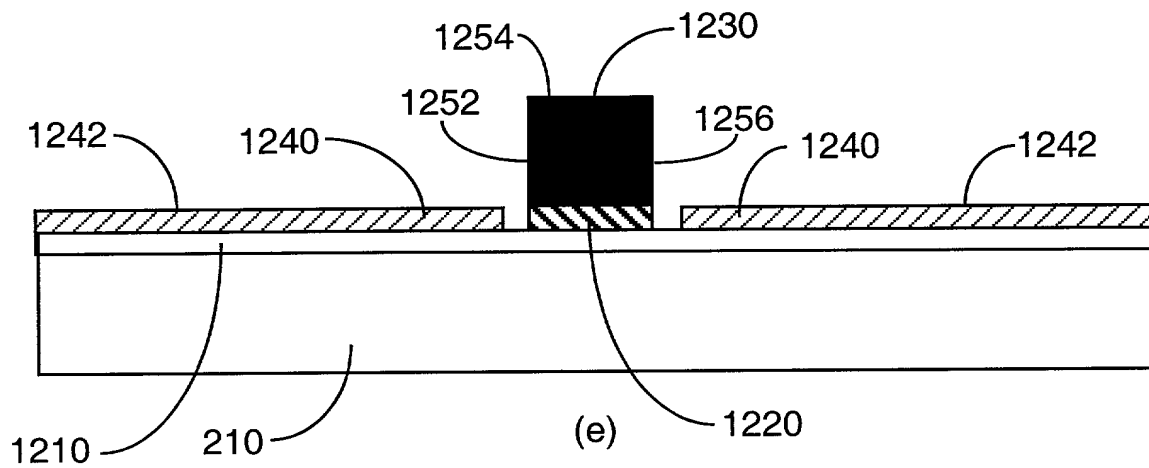
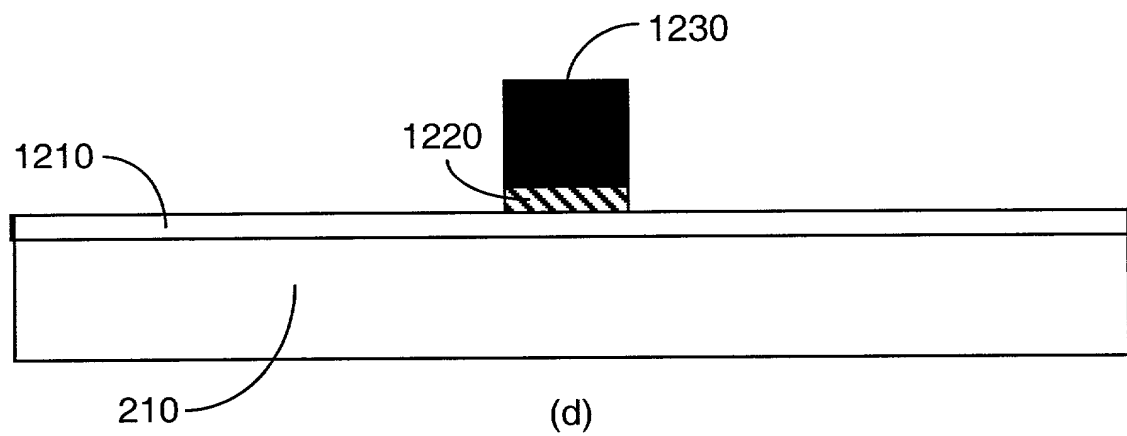


Figure 11

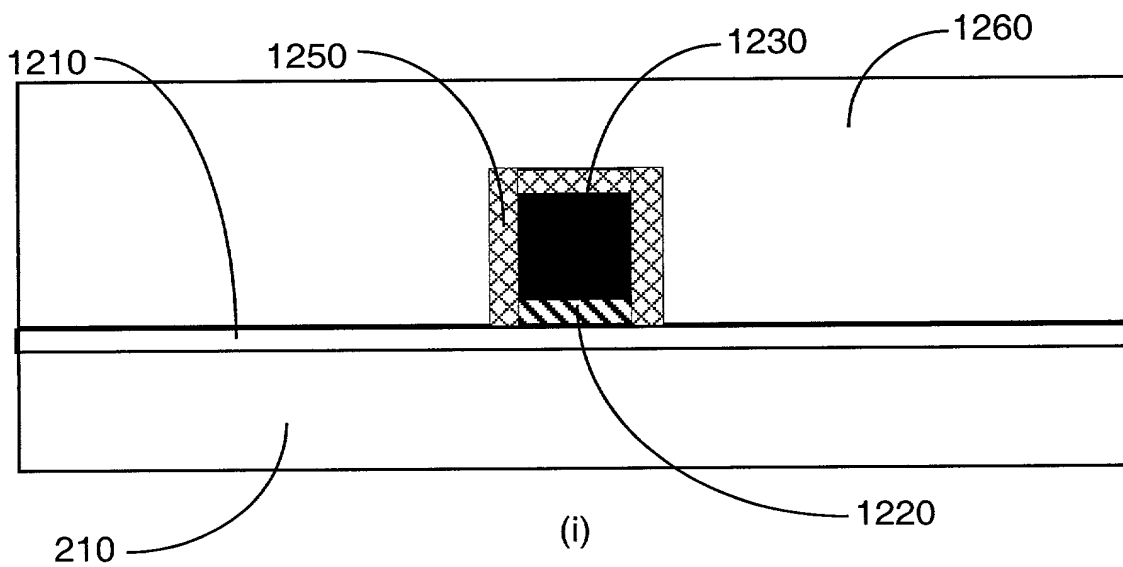
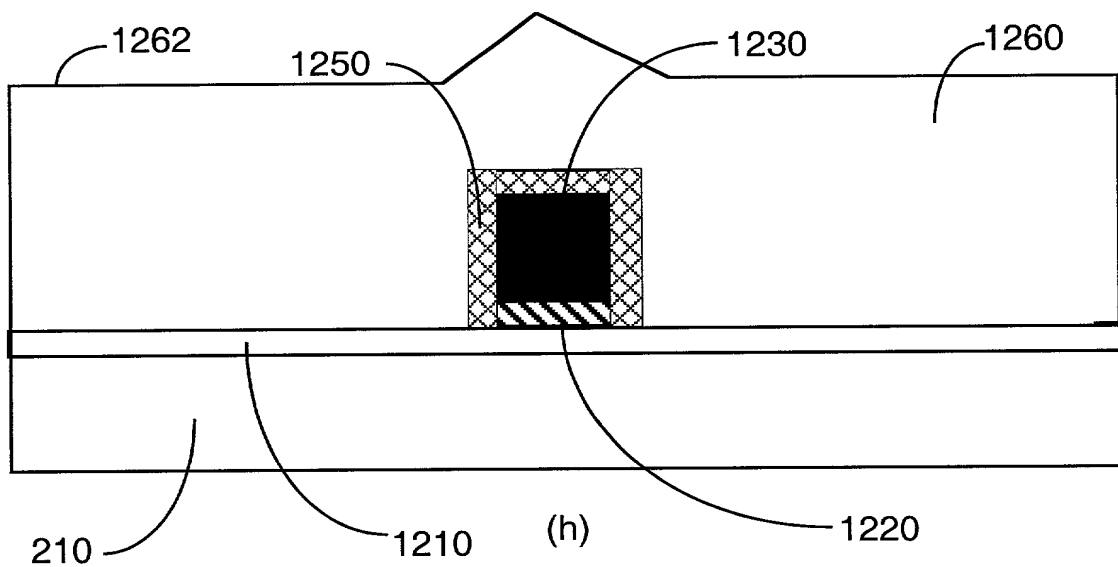
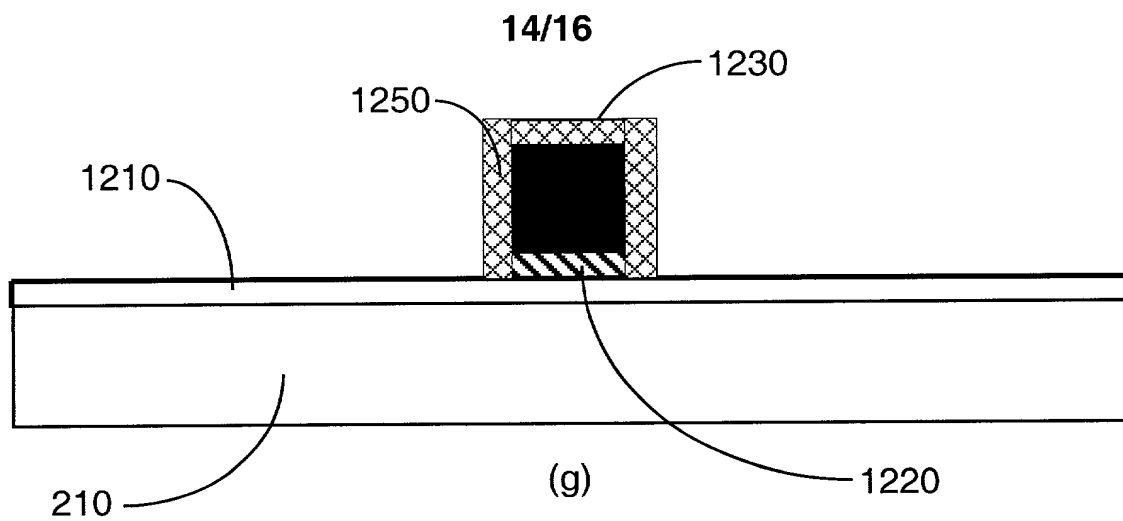


Figure 11

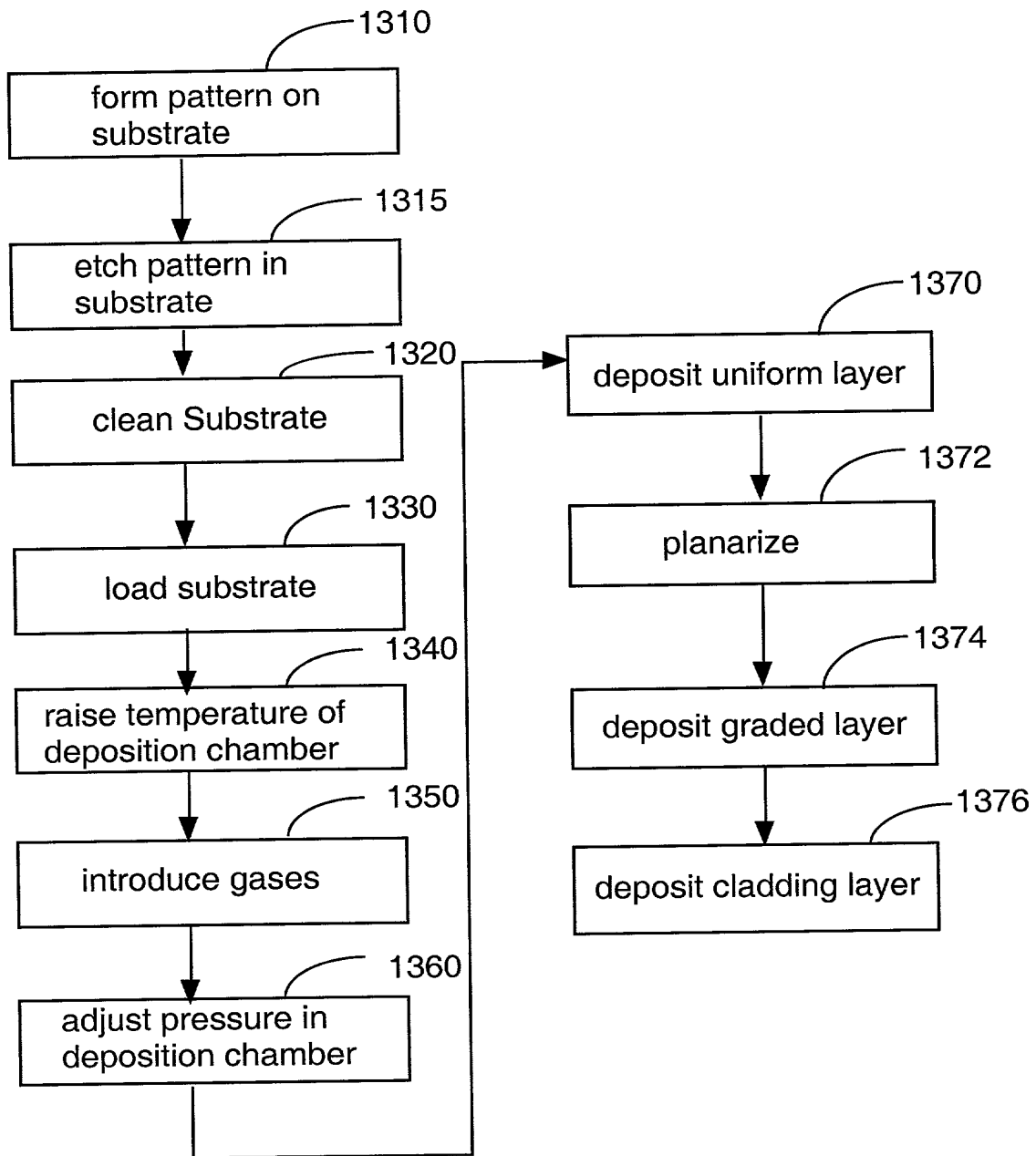


Figure 12

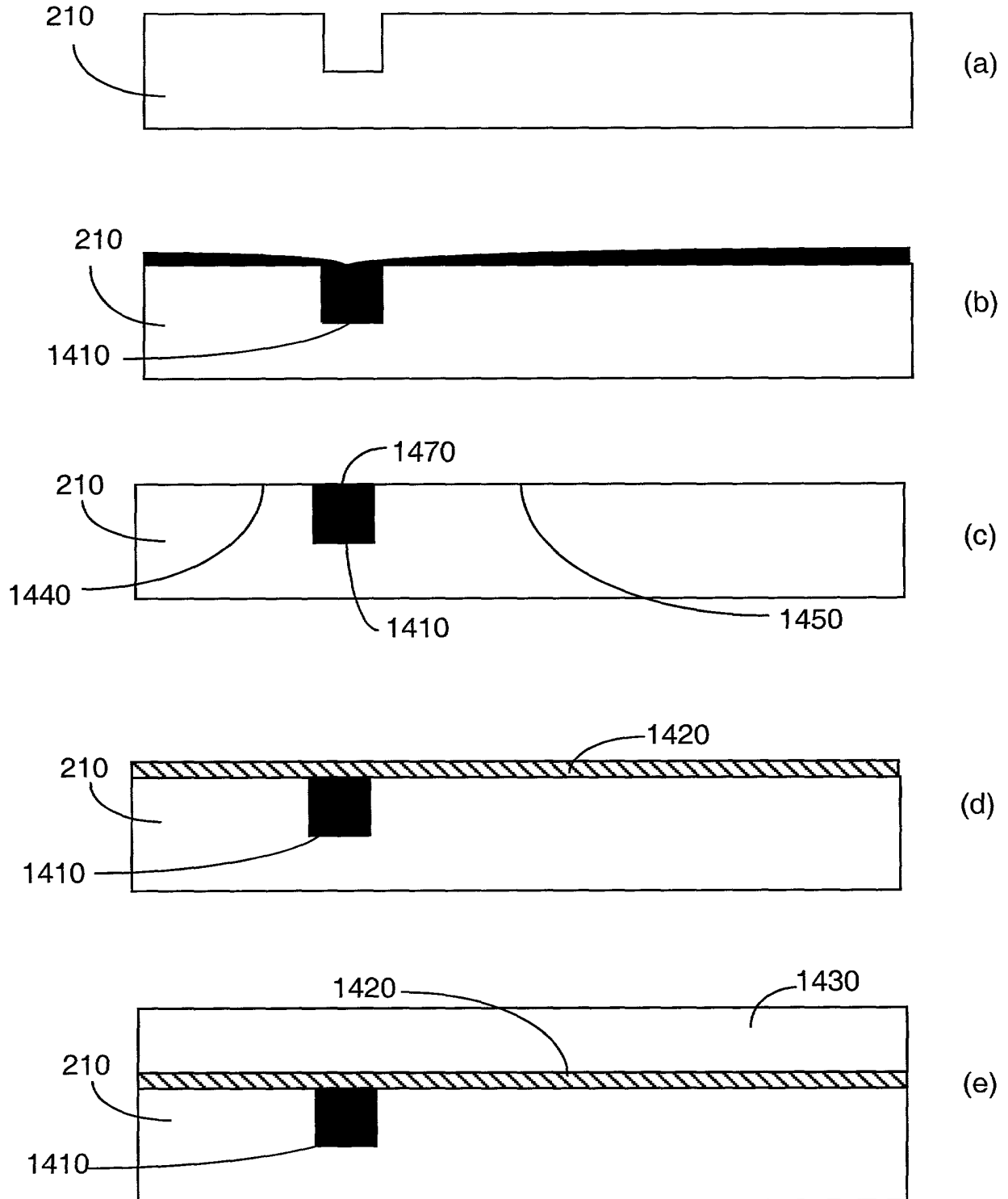


Figure 13